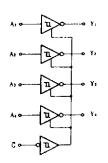
■BLOCK DIAGRAM (½)



#FUNCTION TABLE

Ing	Output		
Ğ	A	Y	
Н	×	Z	
L	Н	L	
L	L	н	

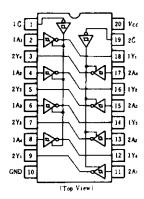
Note) H; high level,

L; low level,

X; irrelevant

Z; off (high-impedance) state of a 3-state output

PIN ARRANGEMENT



ELECTRICAL CHARACTERISTICS ($T_a = -20 \sim +75^{\circ}C$)

	Item	Symbol	Test Conditions		min	typ*	max	Unit	
Input voltage		Vin		••		2.0			v
		VIL				-		0.8	V
Hysteresis		V _T + - V _T -	$V_{\rm CC} = 4.75 \text{V}$			0.2	0.4		V
Output voltage		VOH	$V_{CC} = 4.75 \text{V},$ $V_{IH} = 2 \text{V}$	$V_{IL} = 0.8 \text{V}, I_{OH} = -3 \text{mA}$		2.4		-	
				$V_{IL}=0.5$	/, Іон = −15 mA	2.0	-	-	V
		Vo.	$V_{CC} = 4.75 \text{V}, V_{IH} = 2 \text{V},$ $I_{OL} = 12 \text{mA}$ $V_{IL} = 0.8 \text{V}$ $I_{OL} = 24 \text{mA}$		-	-	0.4	•••	
					Iol = 24 mA	_	-	0.5	V
Output current		І огн	$V_{CC} = 5.25 \text{V}, V_{IH} = 2 \text{V}, V_O = 2.7 \text{V}$		-		20	μА	
		I ozt	$V_{IL}=0.8V V_O=0.4V$		_	-	-20	μА	
I		Iн	$V_{CC} = 5.25 \text{V}, V_I = 2.7 \text{V}$		_	_	20	μA	
		IIL	$V_{CC} = 5.25 \text{V}, V_I = 0.4 \text{V}$		_	-	-0.2	mА	
		Iı	$V_{CC} = 5.25 \text{V}, V_I = 7 \text{V}$			-	0.1	mA	
Short-circu	it output current	Ios	$V_{CC} = 5.25 \text{V}$		-40	-	- 225	mA	
Supply	Outputs high		$V_{CC} = 5.25 \text{V}$			13	23	mА	
	Outputs low	I cc				26	44		
	All outputs disabled				_	29	50		
Input clamp	voltage	Vik	$V_{CC} = 4.75 \text{V}, I_{IN} = -18 \text{mA}$			-	_	-1.5	V

^{*} V_{CC}=5V, Ta=25°C

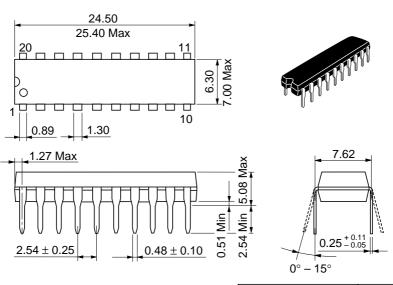
ESWITCHING CHARACTERISTICS ($V_{CC}=5V$, $T_{a}=25^{\circ}C$)

Item	Symbol	Test Conditions	min	typ	max	Unit
Propagation delay time	tplH			9	14	ns
	1PHL	$C_L = 45 \text{pF}, R_L = 667 \Omega$	_	12	18	
Output enable time	tz.L			20	30	ns
	tzn			15	23	ns
Output disable time	tız	$C_L = 5 pF$, $R_L = 667 \Omega$	-	15	25	ns
	tHZ			10	18	ns

Note) Refer to Test Circuit and Waveform of the Common Item

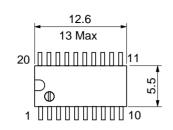
^{**} ICC is measured with all outputs open.

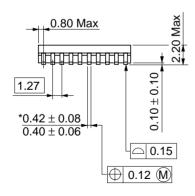
Unit: mm

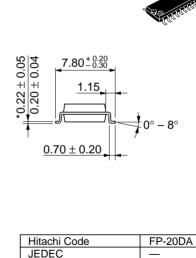


Hitachi Code	DP-20N
JEDEC	_
EIAJ	Conforms
Weight (reference value)	1.26 g

Unit: mm







Weight (reference value)

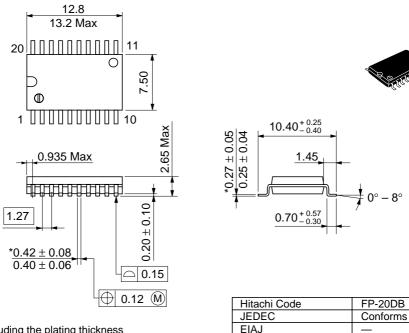
Conforms

0.31 g

EIAJ

*Dimension including the plating thickness
Base material dimension

Unit: mm



Weight (reference value)

0.52 g

*Dimension including the plating thickness
Base material dimension

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HTACHI

Hitachi, Ltd.

Semiconductor & Integrated Circuits.

Nippon Bldg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokyo 100-0004, Japan Tel: Tokyo (03) 3270-2111 Fax: (03) 3270-5109

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For further information write to:

Hitachi Semiconductor (America) Inc. 179 East Tasman Drive, San Jose,CA 95134 Tel: <1> (408) 433-1990 Fax: <1>(408) 433-0223 Hitachi Europe GmbH Electronic components Group Dornacher Stra§e 3 D-85622 Feldkirchen, Munich Germany Tel: <49> (89) 9 9180-0

Fax: <49> (89) 9 29 30 00 Hitachi Europe Ltd. Electronic Components Group. Whitebrook Park Lower Cookham Road Maidenhead

Berkshire SL6 8YA, United Kingdom Tel: <44> (1628) 585000 Fax: <44> (1628) 778322

Hitachi Asia Pte. Ltd. 16 Collyer Quay #20-00 Hitachi Tower Singapore 049318 Tel: 535-2100 Fax: 535-1533

Hitachi Asia Ltd. Taipei Branch Office 3F, Hung Kuo Building. No.167, Tun-Hwa North Road, Taipei (105) Tel: <886> (2) 2718-3666 Fax: <886> (2) 2718-8180

Hitachi Asia (Hong Kong) Ltd. Group III (Electronic Components) 7/F., North Tower, World Finance Centre, Harbour City, Canton Road, Tsim Sha Tsui, Kowloon, Hong Kong Tel: <852> (2) 735 9218

Fax: <852> (2) 730 0281 Telex: 40815 HITEC HX

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